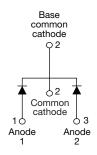


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High Performance Schottky Rectifier, 2 x 15 A

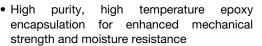




PRODUCT SUMMARY								
Package	TO-263AB (D ² PAK)							
I _{F(AV)}	2 x 15 A							
V_R	30 V							
V _F at I _F	0.47 V							
I _{RM} max.	183 mA at 125 °C							
T _J max.	150 °C							
Diode variation	Common cathode							
E _{AS}	13 mJ							

FEATURES

- 150 °C T_J operation
- · Center tap configuration
- · Very low forward voltage drop
- High frequency operation





ROHS COMPLIANT HALOGEN FREE

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	30	A						
V _{RRM}		30	V						
I _{FSM}	t _p = 5 μs sine	1100	A						
V _F	15 A _{pk} , T _J = 125 °C (per leg)	0.34	V						
T _J	Range	-55 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBRB3030CTLPbF	UNITS						
Maximum DC reverse voltage	V_{R}	30	V						
Maximum working peak reverse voltage	V_{RWM}	30	V						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDI	TIONS	VALUES	UNITS		
Maximum average per leg		_	FOOV shirth and a set T = 101 °C are the small an unsurface.		15	А		
See fig. 5	per device		$I_{F(AV)}$ 50 % duty cycle at T_C = 121 °C rectangular waveform					
Maximum peak one cycle non-repetitive surge current per leg See fig. 7			5 μs sine or 3 μs rect. pulse Following any rated load condition and with		1100			
		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	360			
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 2.9 mH		13	mJ		
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	Α		

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VS-MBRB3030CTLPbF

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		15 A	T _{.1} = 25 °C	0.47	V			
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	30 A	11 = 23 0	0.55				
See fig. 1	VFM ('')	15 A	T _ 105 °C	0.34				
		30 A	T _J = 125 °C	0.45				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V - Poted V	2	mA			
See fig. 2		T _J = 125 °C	V _R = Rated V _R	183				
Threshold voltage	V _{F(TO)}	T - T movimum	T _J = T _J maximum		V			
Forward slope resistance	r _t	ij = ij maximum			mΩ			
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	2840	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 r	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

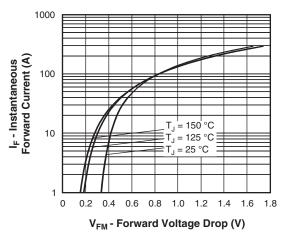
Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C		
Maximum thermal resistance,	per leg	D	DC operation	2.0	°C/W		
junction to case	per package	R_{thJC}	DC operation	1.0			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	G, 11		
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
Marking device			Case style D ² PAK	MBRB30	30CTL		

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T_J = 150 °C

T_J = 125 °C

T_J = 100 °C

T_J = 100 °C

T_J = 75 °C

T_J = 50 °C

T_J = 25 °C

0.01

0 5 10 15 20 25 30

V_B - Reverse Voltage (V)

1000

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

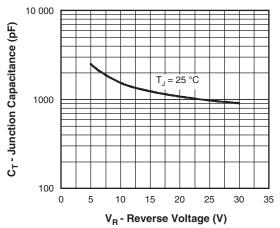


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

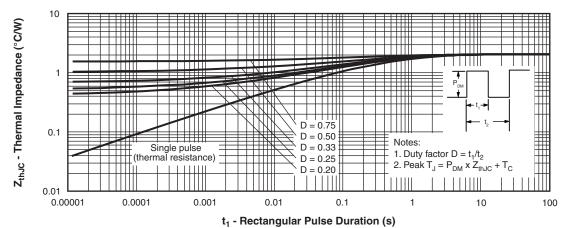


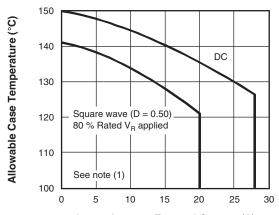
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)





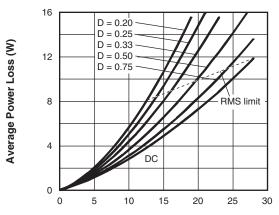
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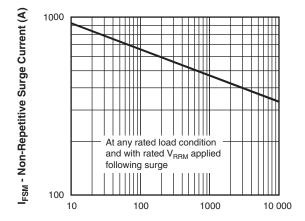
I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)



I_{F(AV)} - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics (Per Leg)



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

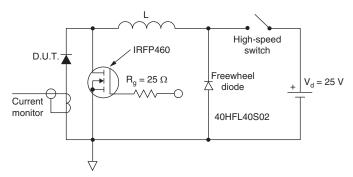


Fig. 8 - Unclamped Inductive Test Circuit

Note

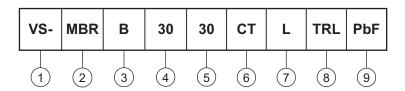
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; I_R \text{ at } V_{R1} = 10 \text{ V}. \end{array}$



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Schottky MBR series

3 $B = D^2PAK$

Current rating (30 = 30 A)

Voltage rating (30 = 30 V)

5 6 CT = center tap (dual)

 $L = low V_F$

• None = tube (50 pieces)

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 • PbF = lead (Pb)-free (for D²PAK tube)

• P = lead (Pb)-free (for D²PAK TRR and TRL)

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95046</u>						
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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